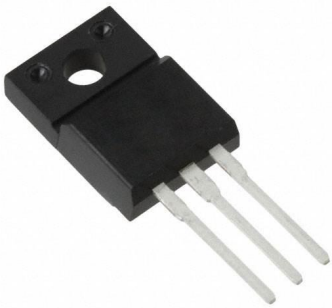


# 2SD2528 Datasheet

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DiGi Electronics Part Number	2SD2528-DG
Manufacturer	<a href="#">Panasonic Electronic Components</a>
Manufacturer Product Number	2SD2528
Description	TRANS NPN 60V 5A TO220D-A1
Detailed Description	Bipolar (BJT) Transistor NPN 60 V 5 A 30MHz 2 W Th rough Hole TO-220D-A1



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

2SD2528

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

60 V

Current - Collector Cutoff (Max):

100 $\mu$ A (ICBO)

Power - Max:

2 W

Operating Temperature:

150°C (TJ)

Package / Case:

TO-220-3 Full Pack

Base Product Number:

2SD252

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

5 A

Vce Saturation (Max) @ Ib, Ic:

300mV @ 100mA, 4A

DC Current Gain (hFE) (Min) @ Ic, Vce:

500 @ 1A, 4V

Frequency - Transition:

30MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-220D-A1

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.29.0075

ECCN:

EAR99

# 2SD2528

## Silicon NPN epitaxial planar type

For power amplification and high-current amplification

### ■ Features

- High forward current transfer ratio  $h_{FE}$
- Satisfactory linearity of forward current transfer ratio  $h_{FE}$
- Full-pack package which can be installed to the heat sink with one screw

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	80	V
Collector-emitter voltage (Base open)	$V_{CEO}$	60	V
Emitter-base voltage (Collector open)	$V_{EBO}$	6	V
Collector current	$I_C$	5	A
Peak collector current	$I_{CP}$	10	A
Base current	$I_B$	1	A
Collector power dissipation	$T_C = 25^\circ\text{C}$	$P_C$	40
			2.0
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

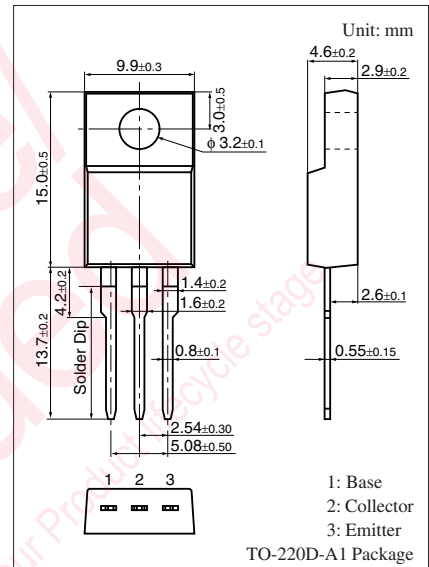
### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

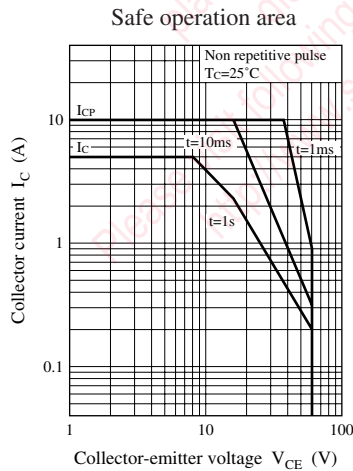
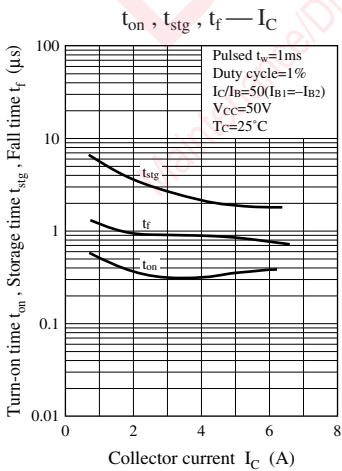
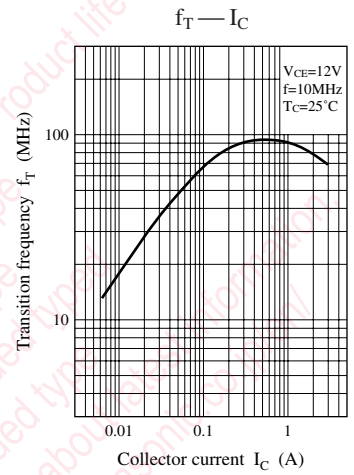
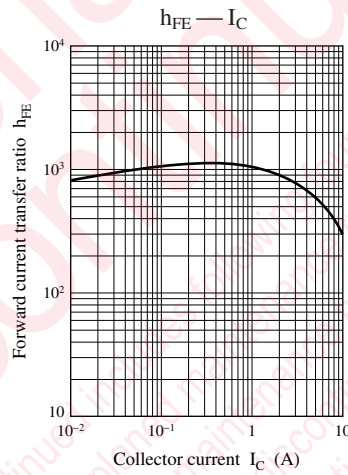
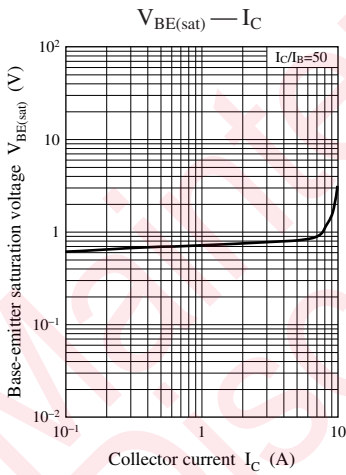
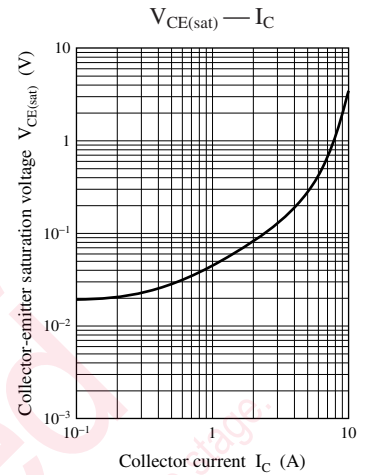
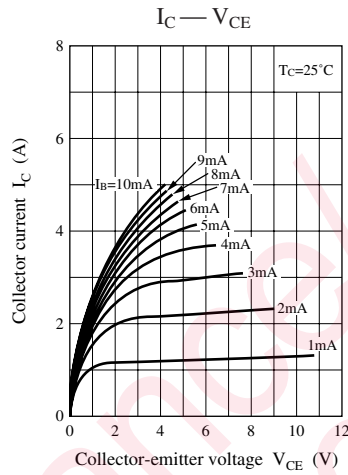
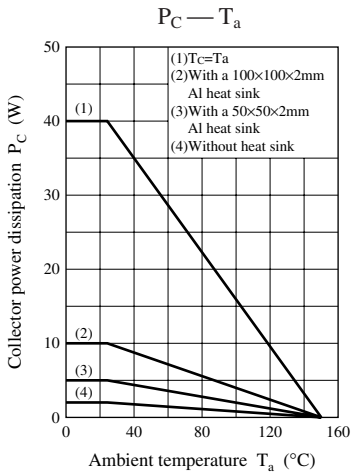
Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 25\text{ mA}, I_B = 0$	60			V	
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 80\text{ V}, I_E = 0$			100	$\mu\text{A}$	
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 6\text{ V}, I_C = 0$			100	$\mu\text{A}$	
Forward current transfer ratio	$h_{FE}^*$	$V_{CE} = 4\text{ V}, I_C = 1\text{ A}$	500		2000	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 4\text{ A}, I_B = 0.1\text{ A}$			0.3	V	
Transition frequency	$f_T$	$V_{CE} = 12\text{ V}, I_C = 0.4\text{ A}, f = 10\text{ MHz}$		30		MHz	
Turn-on time	$t_{on}$	$I_C = 4\text{ A}, I_{B1} = 0.08\text{ A}, I_{B2} = -0.08\text{ A}$ $V_{CC} = 50\text{ V}$		0.4		$\mu\text{s}$	
Storage time	$t_{stg}$				2.0		$\mu\text{s}$
Fall time	$t_f$				0.6		$\mu\text{s}$

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Rank	Q	P
$h_{FE1}$	500 to 1200	800 to 2000





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